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# HN27C256HP/HFP Series

32768-word × 8-bit CMOS One Time Electrically Programmable  
ROM

# HITACHI

ADE-203-  
Maintenance only  
Rev. 0.0  
Dec. 1, 1995

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## Description

The HN27C256HP/HFP is a 32768-word by 8-bit one time electrically programmable ROM. Initially, all bits of the HN27C256HP/HFP are in the „1“ State (Output High). Data is introduced by selectively programming „0“ into the desired bit locations. This device is packaged in a 28-pin plastic package (DIP, SOP). Therefore, this device cannot be re-written.

## Features

- High speed  
Access time: 85/100 ns (max)
- Low power dissipation  
Active mode: 30 mW (typ) (f = 1 MHz)
- High reliability and fast programming  
Programming voltage: +12.5 V DC  
Fast High-Reliability Programming Algorithm available
- Device identifier mode  
Manufacturer code and device code

## Ordering Information

Type No.	Access Time	Package
HN27C256HP-85 HN27C256HP-10	85 ns 100 ns	28-pin plastic DIP (DP-28)
HN27C256HFP-85T HN27C256HFP-10T	85 ns 100 ns	28-pin plastic SOP (FP-28DA)

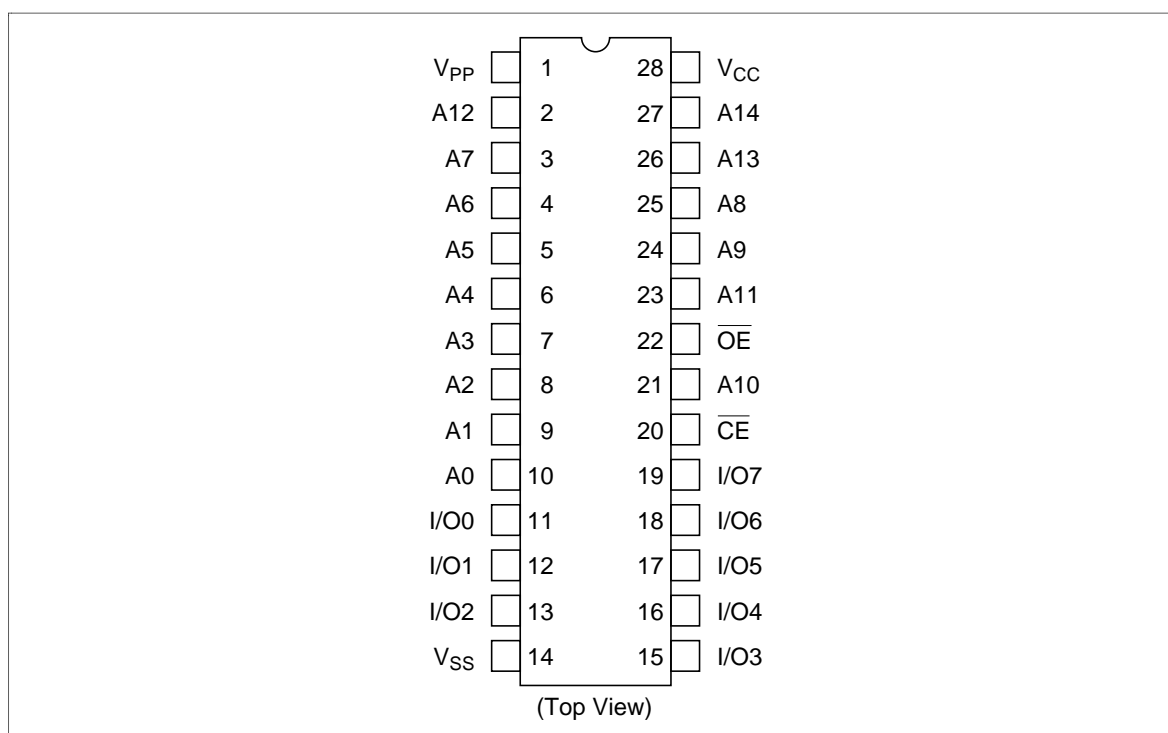
Note: This device is not available for new application.

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## HN27C256HP/HFP Series

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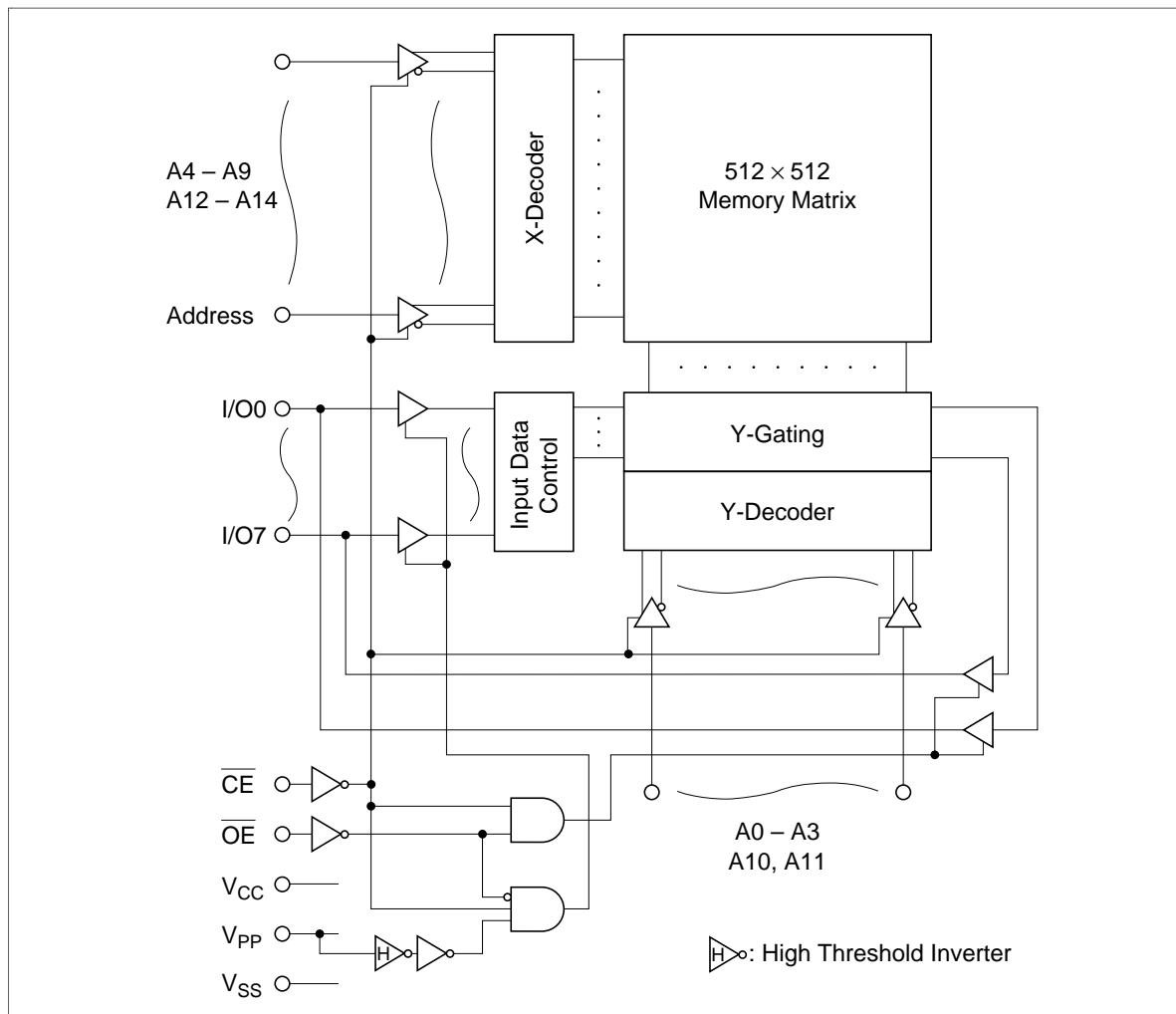
### Pin Arrangement



### Pin Description

Pin Name	Function
A0 – A14	Address
I/O0 – I/O7	Input/output
$\overline{CE}$	Chip enable
$\overline{OE}$	Output enable
$V_{CC}$	Power supply
$V_{PP}$	Programming power supply
$V_{SS}$	Ground

Block Diagram



## HN27C256HP/HFP Series

### Mode Selection

Mode	$\overline{\text{CE}}$ (20)	$\overline{\text{OE}}$ (22)	A9 (24)	V <sub>PP</sub> (1)	V <sub>CC</sub> (28)	I/O (11 – 13, 15 – 19)
Read	V <sub>IL</sub>	V <sub>IL</sub>	X	V <sub>CC</sub>	V <sub>CC</sub>	Dout
Output disable	V <sub>IL</sub>	V <sub>IH</sub>	X	V <sub>CC</sub>	V <sub>CC</sub>	High-Z
Standby	V <sub>IH</sub>	X	X	V <sub>CC</sub>	V <sub>CC</sub>	High-Z
Program	V <sub>IL</sub>	V <sub>IH</sub>	X	V <sub>PP</sub>	V <sub>CC</sub>	Din
Program verify	V <sub>IH</sub>	V <sub>IL</sub>	X	V <sub>PP</sub>	V <sub>CC</sub>	Dout
Optional verify	V <sub>IL</sub>	V <sub>IL</sub>	X	V <sub>PP</sub>	V <sub>CC</sub>	Dout
Program inhibit	V <sub>IH</sub>	V <sub>IH</sub>	X	V <sub>PP</sub>	V <sub>CC</sub>	High-Z
Identifier	V <sub>IL</sub>	V <sub>IL</sub>	V <sub>H</sub> <sup>*2</sup>	V <sub>CC</sub>	V <sub>CC</sub>	Code

Notes: 1. x = Don't care.  
2. V<sub>H</sub> = 12.0 V ± 0.5 V.

### Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
All input and output voltage <sup>*1</sup>	Vin, Vout	−0.6 <sup>*2</sup> to +7.0	V
A9 input voltage <sup>*1</sup>	V <sub>ID</sub>	−0.6 <sup>*2</sup> to +13.5	V
V <sub>PP</sub> voltage <sup>*1</sup>	V <sub>PP</sub>	−0.6 to +13.5	V
V <sub>CC</sub> voltage <sup>*1</sup>	V <sub>CC</sub>	−0.6 to +7.0	V
Operating temperature range	Topr	0 to +70	°C
Storage temperature range	Tstg	−55 to +125	°C
Storage temperature range under bias	Tbias	−10 to +80	°C

Notes: 1. Relative to V<sub>SS</sub>.  
2. Vin, Vout, V<sub>ID</sub> min = −1.0 V for pulse width ≤ 50 ns.

### Capacitance (Ta = 25°C, f = 1 MHz)

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Input capacitance	Cin	—	4	8	pF	Vin = 0 V
Output capacitance	Cout	—	8	12	pF	Vout = 0 V

**Read Operation**

**DC Characteristics** ( $T_a = 0$  to  $+70^\circ\text{C}$ ,  $V_{CC} = 5\text{ V} \pm 10\%$ ,  $V_{PP} = V_{CC}$ )

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Input leakage current	$I_{LI}$	—	—	2	$\mu\text{A}$	$V_{in} = 0\text{ V to } V_{CC}$
Output leakage current	$I_{LO}$	—	—	2	$\mu\text{A}$	$V_{out} = 0\text{ V to } V_{CC}$
$V_{PP}$ current	$I_{PP1}$	—	1	100	$\mu\text{A}$	$V_{PP} = 5.5\text{ V}$
Standby $V_{CC}$ current	$I_{SB}$	—	—	15	$\text{mA}$	$\overline{CE} = V_{IH}$
Operating $V_{CC}$ current	$I_{CC1}$	—	—	30	$\text{mA}$	$\overline{CE} = V_{IL}$ , $I_{out} = 0\text{ mA}$
	$I_{CC2}$	—	—	40	$\text{mA}$	$f = 11.8\text{ MHz}$ , $I_{out} = 0\text{ mA}$
	$I_{CC3}$	—	5	15	$\text{mA}$	$f = 1\text{ MHz}$ , $I_{out} = 0\text{ mA}$
Input low voltage <sup>*3</sup>	$V_{IL}$	$-0.3^{*1}$	—	0.8	$\text{V}$	
Input high voltage <sup>*3</sup>	$V_{IH}$	2.2	—	$V_{CC} + 1.0^{*2}$	$\text{V}$	
Output low voltage	$V_{OL}$	—	—	0.45	$\text{V}$	$I_{OL} = 2.1\text{ mA}$
Output high voltage	$V_{OH1}$	2.4	—	—	$\text{V}$	$I_{OH} = -1.0\text{ mA}$
	$V_{OH2}$	$V_{CC} - 0.7$	—	—	$\text{V}$	$I_{OH} = -100\text{ }\mu\text{A}$

Notes: 1.  $V_{IL}$  min =  $-1.0\text{ V}$  for pulse width  $\leq 50\text{ ns}$ .

2.  $V_{IH}$  max =  $V_{CC} + 1.5\text{ V}$  for pulse width  $\leq 20\text{ ns}$ .

If  $V_{IH}$  is over the specified maximum value, read operation cannot be guaranteed.

3. Only defined for DC function test.  $V_{IL}$  max =  $0.45\text{ V}$ ,  $V_{IH}$  min =  $2.4\text{ V}$  for AC function test.

## HN27C256HP/HFP Series

**AC Characteristics** ( $T_a = 0$  to  $+70^\circ\text{C}$ ,  $V_{CC} = 5\text{ V} \pm 10\%$ ,  $V_{PP} = V_{CC}$ )

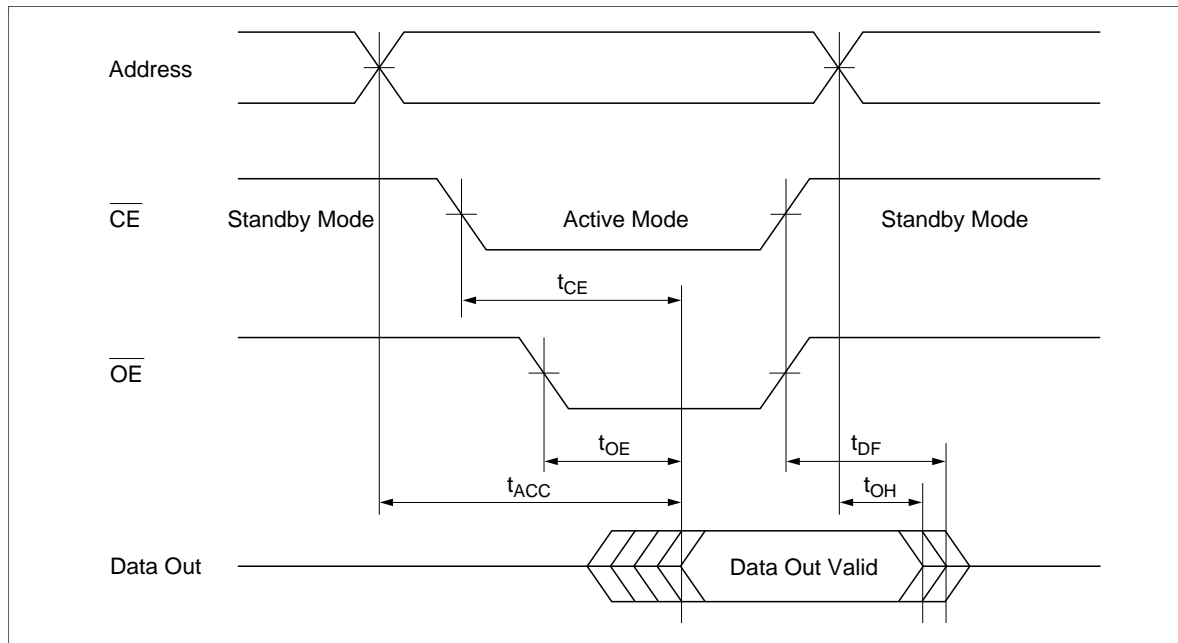
### Test Conditions

- Input pulse levels: 0.45 V to 2.4 V
- Input rise and fall time:  $\leq 10\text{ ns}$
- Output load: 1TTL gate + 100 pF
- Reference levels for measuring timing: Inputs; 1.5 V  
Outputs; 1.5 V

Parameter	Symbol	HN27C256HP-85 HN27C256HFP-85T		HN27C256HP-10 HN27C256HFP-10T		Unit	Test Conditions
		Min	Max	Min	Max		
Address to output delay	$t_{ACC}$	—	85	—	100	ns	$\overline{CE} = \overline{OE} = V_{IL}$
$\overline{CE}$ to output delay	$t_{CE}$	—	85	—	100	ns	$\overline{OE} = V_{IL}$
$\overline{OE}$ to output delay	$t_{OE}$	—	45	—	55	ns	$\overline{CE} = V_{IL}$
$\overline{OE}$ high to output float	$t_{DF}$	0	30	0	35	ns	$\overline{CE} = V_{IL}$
Address to output hold	$t_{OH}$	5	—	5	—	ns	$\overline{CE} = \overline{OE} = V_{IL}$

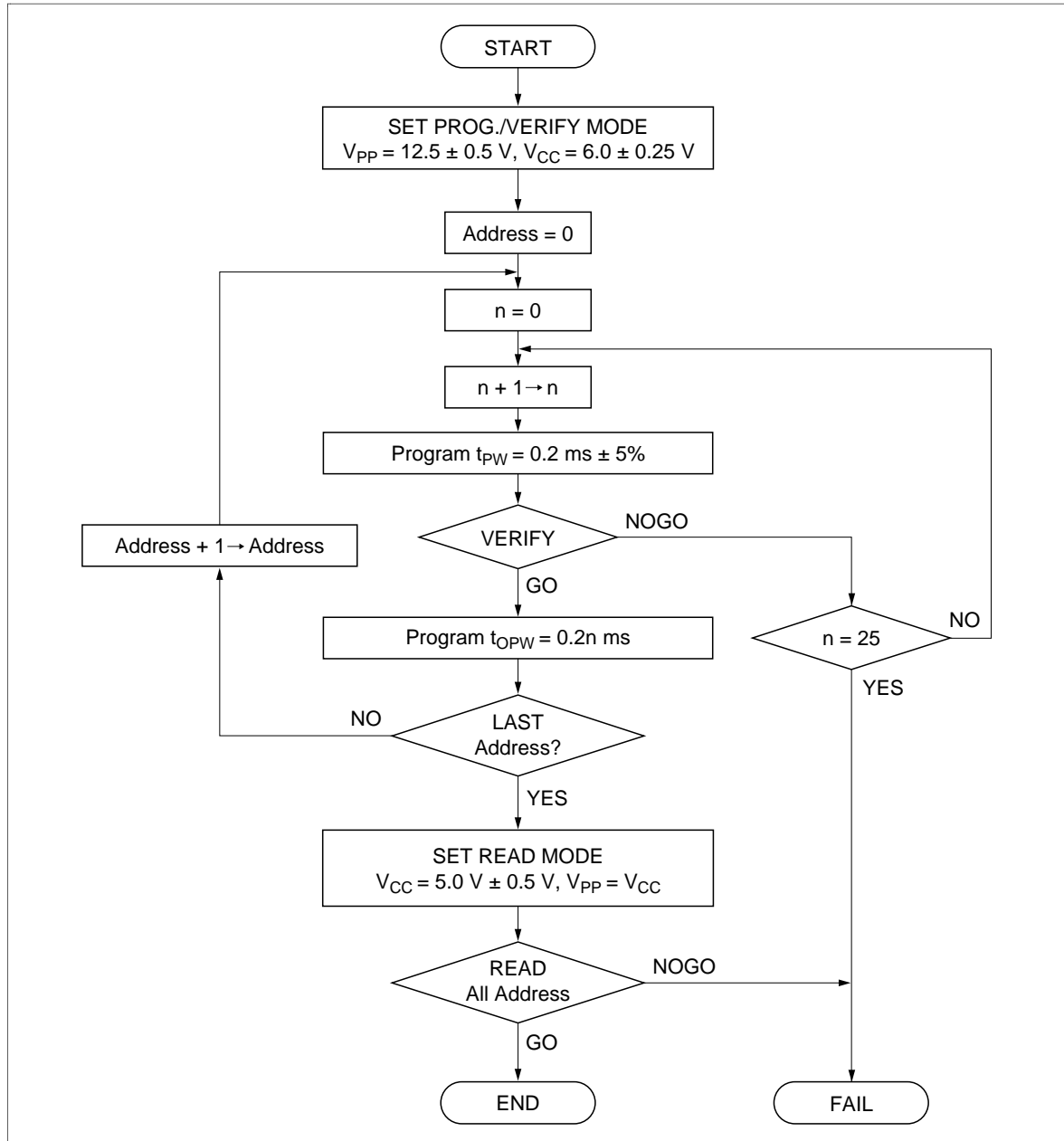
Note:  $t_{DF}$  is defined as the time at which the output achieves the open circuit condition and data is no longer driven.

### Read Timing Waveform



### Fast High-Reliability Programming

This device can be applied the Fast High-Reliability Programming Algorithm shown in following flowchart. This algorithm offers both faster programming time and high reliability data retention. A theoretical programming time (except blank checking and verifying time) is one-tenth of conventional high performance programming algorithm's. Regarding the model and software version of the programmers available this algorithm, please contact programmer maker.



## HN27C256HP/HFP Series

**DC Characteristics** ( $T_a = 25^\circ\text{C} \pm 5^\circ\text{C}$ ,  $V_{CC} = 6\text{ V} \pm 0.25\text{ V}$ ,  $V_{PP} = 12.5\text{ V} \pm 0.5\text{ V}$ )

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Input leakage current	$I_{LI}$	—	—	2	$\mu\text{A}$	$V_{in} = 0\text{ V to } V_{CC}$
$V_{PP}$ supply current	$I_{PP}$	—	—	30	$\text{mA}$	$\overline{CE} = V_{IL}$
Operating $V_{CC}$ current	$I_{CC}$	—	—	30	$\text{mA}$	
Input low level	$V_{IL}$	$-0.1^{*5}$	—	0.8	$\text{V}$	
Input high level	$V_{IH}$	2.2	—	$V_{CC} + 0.5^{*6}$	$\text{V}$	
Output low voltage during verify	$V_{OL}$	—	—	0.45	$\text{V}$	$I_{OL} = 2.1\text{ mA}$
Output high voltage during verify	$V_{OH}$	2.4	—	—	$\text{V}$	$I_{OH} = -400\text{ }\mu\text{A}$

- Notes: 1.  $V_{CC}$  must be applied simultaneously or before  $V_{PP}$  and removed simultaneously or after  $V_{PP}$ .  
 2.  $V_{PP}$  must not exceed 13.5 V including overshoot.  
 3. An influence may be had upon device reliability if the device is installed or removed while  $V_{PP} = 12.5\text{ V}$ .  
 4. Do not alter  $V_{PP}$  either  $V_{IL}$  to 12.5 V or 12.5 V to  $V_{IL}$  when  $\overline{CE} = \text{Low}$ .  
 5.  $V_{IL}$  min =  $-0.6\text{ V}$  for pulse width  $\leq 20\text{ ns}$ .  
 6. If  $V_{IH}$  is over the specified maximum value, programming operation cannot be guaranteed.



**AC Characteristics** ( $T_a = 25^\circ\text{C} \pm 5^\circ\text{C}$ ,  $V_{CC} = 6\text{ V} \pm 0.25\text{ V}$ ,  $V_{PP} = 12.5\text{ V} \pm 0.5\text{ V}$ )

**Test Conditions**

- Input pulse levels: 0.45 V to 2.4 V
- Input rise and fall time:  $\leq 20\text{ ns}$
- Reference levels for measuring timing: Inputs; 0.8 V and 2.0 V  
Outputs; 0.8 V and 2.0 V

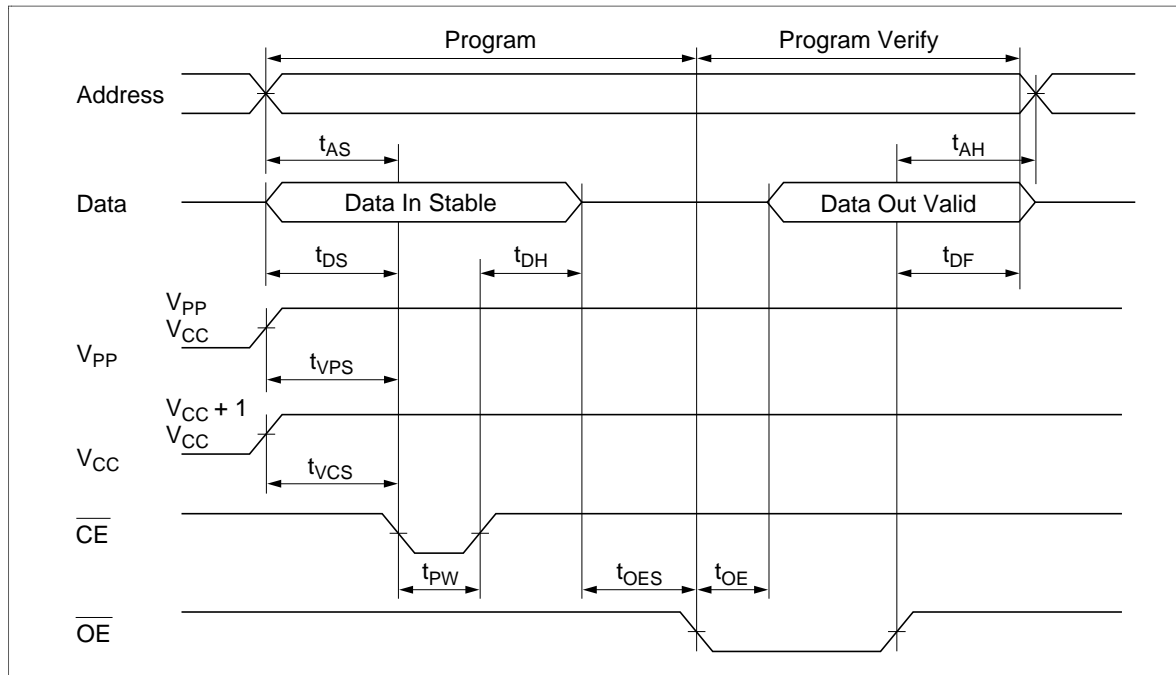
Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Address setup time	$t_{AS}$	2	—	—	$\mu\text{s}$	
$\overline{OE}$ setup time	$t_{OES}$	2	—	—	$\mu\text{s}$	
Data setup time	$t_{DS}$	2	—	—	$\mu\text{s}$	
Address hold time	$t_{AH}$	0	—	—	$\mu\text{s}$	
Data hold time	$t_{DH}$	2	—	—	$\mu\text{s}$	
$V_{PP}$ setup time	$t_{VPS}$	2	—	—	$\mu\text{s}$	
$V_{CC}$ setup time	$t_{VCS}$	2	—	—	$\mu\text{s}$	
$\overline{CE}$ initial programming pulse width	$t_{PW}$	0.19	0.20	0.21	ms	
$\overline{CE}$ over programming pulse width	$t_{OPW}^{*1}$	0.19	—	5.25	ms	
Data valid from $\overline{OE}$	$t_{OE}$	0	—	150	ns	
$\overline{OE}$ to output float delay	$t_{DF}^{*2}$	—	—	130	ns	

Notes: 1. Refer to the Fast High-Reliability Programming Flowchart for  $t_{OPW}$ .

2.  $t_{DF}$  is defined as the time at which the output achieves the open circuit condition and data is no longer driven.

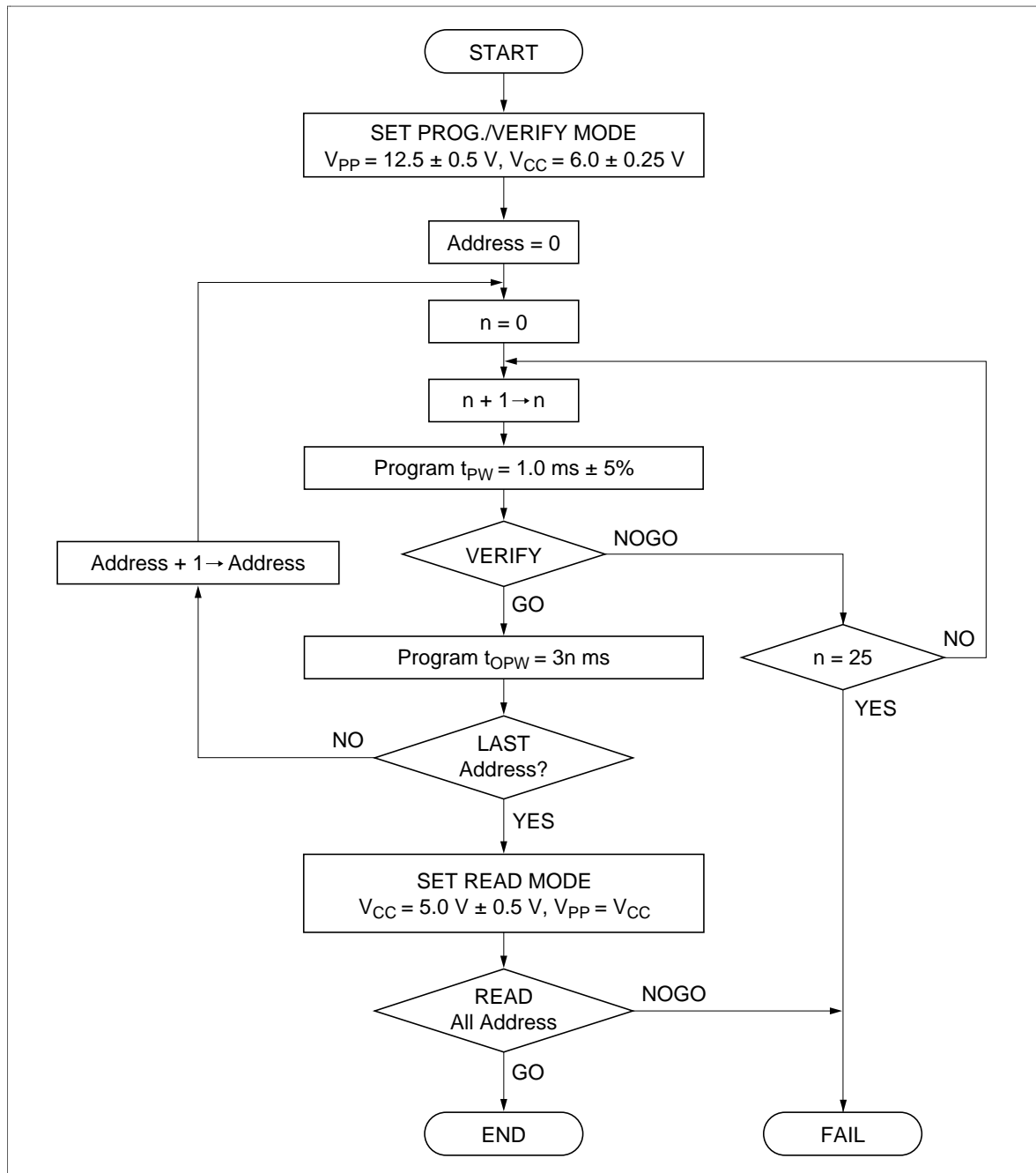
## HN27C256HP/HFP Series

### Fast High-Reliability Programming Timing Waveform



### High Performance Programming

This device can be applied the high performance programming algorithm shown in following flowchart. This algorithm is as same as our 256-kbit EPROM series so existing programmers can be used with this device. This algorithm allows to obtain faster programming time without any voltage stress to the device nor deterioration in reliability of programmed data.



## HN27C256HP/HFP Series

**DC Characteristics** ( $T_a = 25^\circ\text{C} \pm 5^\circ\text{C}$ ,  $V_{CC} = 6\text{ V} \pm 0.25\text{ V}$ ,  $V_{PP} = 12.5\text{ V} \pm 0.5\text{ V}$ )

Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Input leakage current	$I_{LI}$	—	—	2	$\mu\text{A}$	$V_{in} = 0\text{ V to } V_{CC}$
$V_{PP}$ supply current	$I_{PP}$	—	—	30	$\text{mA}$	$\overline{CE} = V_{IL}$
Operating $V_{CC}$ current	$I_{CC}$	—	—	30	$\text{mA}$	
Input low level	$V_{IL}$	$-0.1^{*5}$	—	0.8	$\text{V}$	
Input high level	$V_{IH}$	2.2	—	$V_{CC} + 0.5^{*6}$	$\text{V}$	
Output low voltage during verify	$V_{OL}$	—	—	0.45	$\text{V}$	$I_{OL} = 2.1\text{ mA}$
Output high voltage during verify	$V_{OH}$	2.4	—	—	$\text{V}$	$I_{OH} = -400\text{ }\mu\text{A}$

- Notes:
1.  $V_{CC}$  must be applied simultaneously or before  $V_{PP}$  and removed simultaneously or after  $V_{PP}$ .
  2.  $V_{PP}$  must not exceed 13.5 V including overshoot.
  3. An influence may be had upon device reliability if the device is installed or removed while  $V_{PP} = 12.5\text{ V}$ .
  4. Do not alter  $V_{PP}$  either  $V_{IL}$  to 12.5 V or 12.5 V to  $V_{IL}$  when  $\overline{CE} = \text{Low}$ .
  5.  $V_{IL\text{ min}} = -0.6\text{ V}$  for pulse width  $\leq 20\text{ ns}$ .
  6. If  $V_{IH}$  is over the specified maximum value, programming operation cannot be guaranteed.

**AC Characteristics** ( $T_a = 25^\circ\text{C} \pm 5^\circ\text{C}$ ,  $V_{CC} = 6\text{ V} \pm 0.25\text{ V}$ ,  $V_{PP} = 12.5\text{ V} \pm 0.5\text{ V}$ )

**Test Conditions**

- Input pulse levels: 0.45 V to 2.4 V
- Input rise and fall time:  $\leq 20\text{ ns}$
- Reference levels for measuring timing: Inputs; 0.8 V and 2.0 V  
Outputs; 0.8 V and 2.0 V

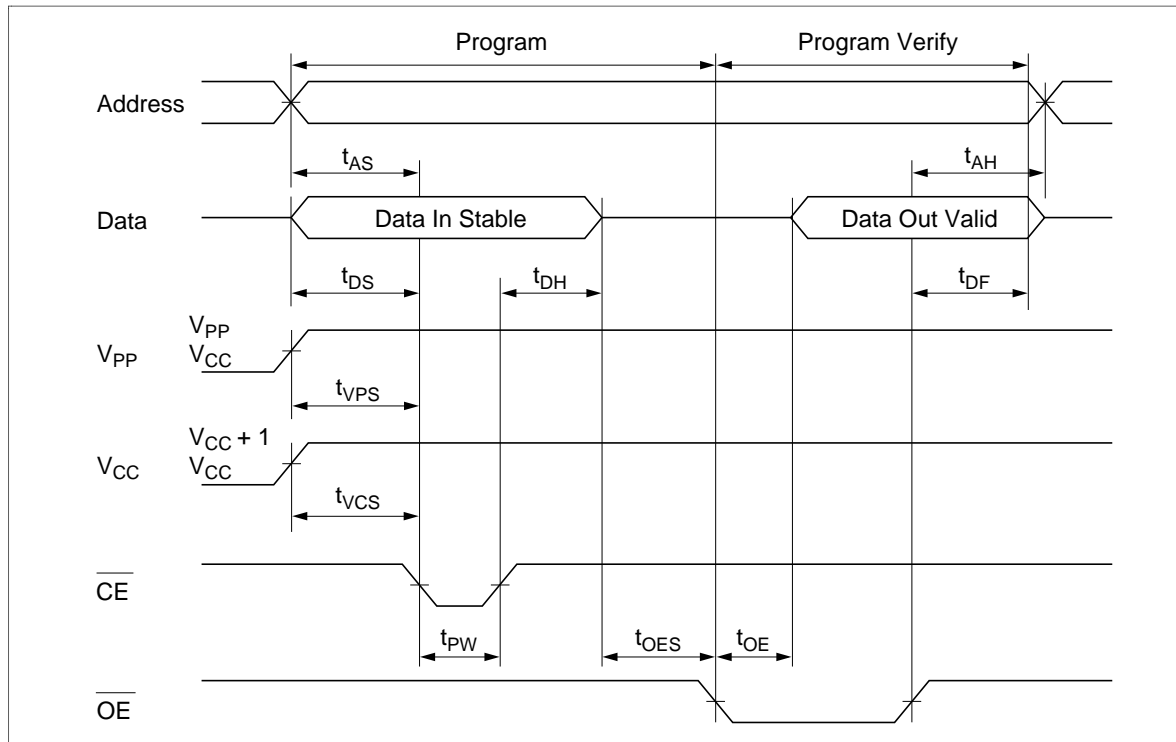
Parameter	Symbol	Min	Typ	Max	Unit	Test Conditions
Address setup time	$t_{AS}$	2	—	—	$\mu\text{s}$	
$\overline{OE}$ setup time	$t_{OES}$	2	—	—	$\mu\text{s}$	
Data setup time	$t_{DS}$	2	—	—	$\mu\text{s}$	
Address hold time	$t_{AH}$	0	—	—	$\mu\text{s}$	
Data hold time	$t_{DH}$	2	—	—	$\mu\text{s}$	
$V_{PP}$ setup time	$t_{VPS}$	2	—	—	$\mu\text{s}$	
$V_{CC}$ setup time	$t_{VCS}$	2	—	—	$\mu\text{s}$	
$\overline{CE}$ initial programming pulse width	$t_{PW}$	0.95	1.0	1.05	ms	
$\overline{CE}$ over programming pulse width	$t_{OPW}^{*1}$	2.85	—	78.75	ms	
Data valid from $\overline{OE}$	$t_{OE}$	0	—	150	ns	
$\overline{OE}$ to output float delay	$t_{DF}^{*2}$	—	—	130	ns	

Notes: 1. Refer to the high performance programming flowchart for  $t_{OPW}$ .

2.  $t_{DF}$  is defined as the time at which the output achieves the open circuit condition and data is no longer driven.

## HN27C256HP/HFP Series

### High Performance Programming Timing Waveform



## Mode Description

### Device Identifier Mode

Programming condition of OTPROM is various according to OTPROM manufacturers and device types. It may cause miss operation. To countermeasure it, some OTPROMs provide maker identifier code. Users can write OTPROM by reading out write condition coded before shipped. Some commercial programmers can set write condition by recognizing this code. This function enables effective program. Regarding commercial programmers that can recognize this device's identifier code, please contact programmer maker.

	A0	I/O7	I/O6	I/O5	I/O4	I/O3	I/O2	I/O1	I/O0	
Identifier	(10)	(19)	(18)	(17)	(16)	(15)	(13)	(12)	(11)	Hex Data
Manufacturer code	V <sub>IL</sub>	0	0	0	0	0	1	1	1	07
Device code	V <sub>IH</sub>	0	0	1	1	0	0	0	1	31

Notes: 1. A9 = 12.0 V  $\pm$  0.5 V.  
 2. A1 – A8, A10 – A14,  $\overline{\text{CE}}$ ,  $\overline{\text{OE}}$  = V<sub>IL</sub>.

### Recommended Screening Conditions

Before mounting, please make the screening (baking without bias) shown in the right.

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## HN27C256HP/HFP Series

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Program and  
Verify  
by Programmer

Baking at  
125 to 150°C  
for 24 to 48 hrs

Ensuring  
Read-out

Mounting

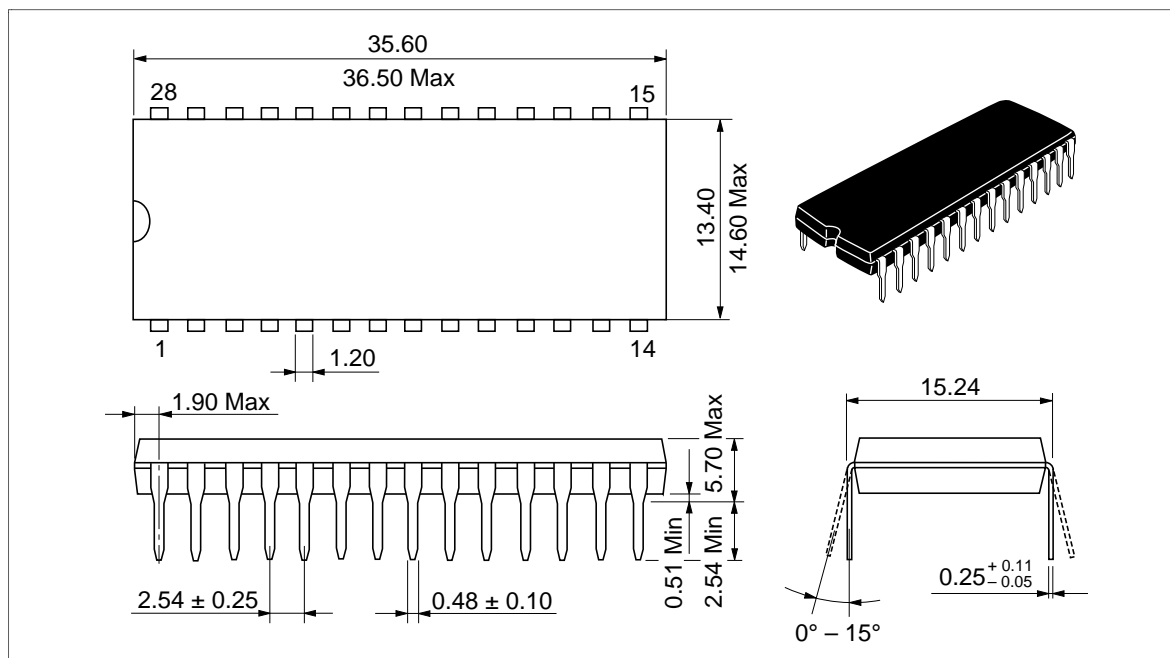
Recommended  
Screening conditions

## HN27C256HP/HFP Series

### Package Dimensions

#### HN27C256HP Series (DP-28)

Unit: mm



#### HN27C256HFP Series (FP-28DA)

Unit: mm

